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			Danicel C. Edelstein et al.			
			FILING		GROUP	
U.S. PATENT DOCUMENTS						
'EXAMINER INITIALS	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
<i>PR</i>	US2002/0172025	11/2002	Megahed et al.			
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<i>✓</i>	WO03017479A2	2/2003	PCT			
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EXAMINER <i>Jenna Brink</i>	DATE CONSIDERED <i>4/29/05</i>					
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<i>PJ</i>		Edelstein et al., SPIRAL AND SOLENOIDAL INDUCTOR STRUCTURES ON SILICON USING CU-DAMASCENE INTERCONNECTS, 1998 IEEE, pages 18-20.					
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EXAMINER <i>Jeanne Kral</i>		DATE CONSIDERED <i>4/29/05</i>					
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